

±12kV ESD-Protected, Slew-Rate-Limited, Fail-Safe, True RS-485 Transceivers

UM3352E SOP8/DIP8

General Description

The UM3352E series are ± 12 kV ESD-protected, high-speed transceivers for RS-485 communication that contain one driver and one receiver. The device features fail-safe circuitry, which guarantees a logic-high receiver output when the receiver inputs are open, shorted or idle. This means that the receiver output will be logic high if all transmitters on a terminated bus are disabled (high impedance). The UM3352E features reduced slew-rate driver that minimizes EMI and reduces reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps. It also features enhanced ESD protection. All transmitter outputs and receiver inputs are protected to ± 12 kV using IEC61000-4-2, Air-Gap Discharge.

The transceivers typically draw 400μ A of supply current when unloaded, or when fully loaded with the drivers disabled. The device has a 1/8-unit-load receiver input impedance that allows up to 256 transceivers on the bus and are intended for half-duplex communications.

Applications

- RS-485 Transceivers
- Level Translators
- Industrial-Control Local Area Networks
- Transceivers for EMI-Sensitive Applications

Features

- ESD Protection for RS-485 I/O Pins ±12kV—IEC61000-4-2, Air-Gap Discharge
- True Fail-Safe Receiver while Maintaining EIA/TIA-485 Compatibility
- Enhanced Slew-Rate Limiting Facilitates Error-Free Data Transmission
- 2nA Low-Current Shutdown Mode
- -7V to +12V Common-Mode Input Voltage Range
- Allows up to 256 Transceivers on the Bus
- Thermal Shutdown
- Current-Limiting for Driver Overload Protection

Ordering Information

Part Number	Operating Temperature	Mark Code	Package Type
UM3352EESA	-40°C to +85°C	UM3352EESA	SOP8
UM3352EEPA	-40°C to +85°C	UM3352EEPA	DIP8

Selection Guide

Part Number	Guaranteed Date Rate (Mbps)	Low-Power Shutdown	Slew-Rate Limited	Driver/ Receiver Enable	Shutdown Current (nA)	Transceivers On Bus	±12kV ESD Protection
UM3352E	0.5	Yes	Yes	Yes	2	256	Yes



Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	+7	V
	Control Input Voltage (/RE, DE)	-0.3V to (V _{CC} + 0.3V)	V
	Driver Input Voltage (DI)	-0.3V to (V _{CC} + 0.3V)	V
	Driver Output Voltage (A, B)	-7.5 to +12.5	V
	Receiver Input Voltage (A, B)	-7.5 to +12.5	V
	Receiver Output Voltage (RO)	-0.3V to (V _{CC} + 0.3V)	V
T _A	Ambient Temperature	-40 to +85	°C
T _{STG}	Storage Temperature Range	-65 to +160	°C
T _L	Lead Temperature for Soldering 10 seconds	+300	°C

DC Electrical Characteristics

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.) (Note 1)$

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
SUPPLY CURRENT							
Supply Current	I _{CC}	No load, DI = GND	$DE = V_{CC},$ $\overline{R E} = 0V \text{ or } V_{CC}$	0.3			mA
Suppry Current	100	or V _{CC}	$DE = 0V,$ $\overline{RE} = 0V$	0.25			IIIA
Supply Current in Shutdown Mode	$\mathbf{I}_{\mathrm{SHDN}}$	DE = GN	D, $\overline{RE} = V_{CC}$	0.002		10	μΑ
LOGIC							
Input High Voltage	$\mathbf{V}_{\mathrm{IH1}}$	DE,	DI, RE	2.0			V
Input Low Voltage	V_{IL1}	DE,	DI, RE			0.8	V
DI Input Hysteresis	$V_{\rm HYS}$	UM3085E		100			mV
DRIVER							
Differential Driver Output	V _{OD1}	No Lo	oad, Figure 2			5	V
Differential Driver Output	V _{OD2}	Figure	2, $R = 50\Omega$	1.5			V
Change-in-Magnitude of Differential Output Voltage	ΔV_{OD}	Figure 2, $R = 50\Omega$; (Note 2)				0.2	V
Driver Common-Mode Output Voltage	V _{OC}	Figure 2, $R = 50\Omega$				3.0	V
Change-in-Magnitude of Common-Mode Voltage	ΔV_{OC}	Figure 2, $R = 50\Omega$; (Note 2)				0.2	V
Driver Short-Circuit Output	Т	Vot	$_{\rm JT}$ = -7V		-250		mA
Current (Note 3)	I _{osd}	Vot	$_{\rm JT} = 12 \rm V$		250		IIIA



DC Electrical Characteristics (Continued)

(V_{CC} = +5V ± 5%, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC}= +5V and T_A = +25°C.) (Note 1)

Parameter	Symbol	Test Co	nditions	Min	Тур	Max	Unit
RECEIVER							
Receiver Differential Threshold Voltage	\mathbf{V}_{TH}	-7V≤V _{CM} ≤12V		-200		-50	mV
Receiver Input Hysteresis	ΔV_{TH}	V _{CM}	1=0V		25		mV
Receiver Input Resistance	R _{IN}	-7V≤V	$_{CM} \leq 12V$	96			KΩ
Input Current (A and B)	T	DE = GND,	$V_{IN} = 12V$			1.0	mA
input Current (A and B)	I _{IN2}	V _{CC} = GND or 5V	$V_{IN} = -7V$			-0.8	IIIA
Receiver Output High Voltage	V _{OH}	$I_0 = -1.5 mA$,	$V_{ID} = 200 mV$	V _{CC} -1.5			v
Receiver Output Low Voltage	V _{OL}	$I_0 = 2.5 \text{mA}, V_{\text{ID}} = 200 \text{mV}$				0.4	v
Three-State Output Current at Receiver	I _{ozr}	$V_{CC} = 5V, 0V \le V_O \le V_{CC}$				±1	μΑ
Receiver Output Short Circuit Current	I _{OSR}	$0V \le V_{RO} \le V_{CC}$		±8		±60	mA
ESD Protection						-	
ESD Protection for A, B		IEC61000-4-2	2 Air Discharge		±12		kV

Note 1: All currents into the device are positive; all currents out of the device are negative. All voltages are referred to device ground unless otherwise noted.

Note 2: ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.

Note 3: Maximum current level applies to peak current just prior to fold back current limiting; minimum current level applies during current limiting.



Switching Characteristics

(V_{CC} = +5V ± 5%, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC} = +5V and T_A = +25°C.)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Maximum Data Rate	f _{MAX}			500		kbps	
	t _{DPLH}	Figures 3 and 7, $R_{DIFF} = 54\Omega$,	250	720	1000		
Driver Input-to-Output	t _{DPHL}	$C_{L1} = C_{L2} = 100 \text{pF}$	250	720	1000	ns	
Driver Output Skew t _{DPLH} - t _{DPHL}	t _{DSKEW}	Figures 3 and 7, $R_{DIFF} = 54\Omega$, $C_{L1} = C_{L2} = 100 pF$		3	100	ns	
Driver Rise or Fall Time	t _{DR} , t _{DF}	Figures 3 and 7, $R_{DIFF} = 54\Omega$, $C_{L1} = C_{L2} = 100 pF$	200	530	750	ns	
Driver Enable to Output High	t _{DZH}	Figures 4 and 8, $C_L = 100 pF$, S2 closed			2500	ns	
Driver Enable to Output Low	t _{DZL}	Figures 4 and 8, $C_L = 100 pF$, S1 closed			2500	ns	
Driver Disable Time from Low	t _{DLZ}	Figures 4 and 8, $C_L = 15 pF$, S1 closed			100	ns	
Driver Disable Time from High	t _{DHZ}	Figures 4 and 8, $C_L = 15 pF$, S2 closed			100	ns	
Receiver Input to Output	t _{RPLH} , t _{RPHL}	$ V_{ID} \!\geq\!\!2.0V;$ rise and fall time of $V_{ID}\!\leq\!\!15\text{ns}$		127	200	ns	
Differential Receiver Skew t _{RPLH} - t _{RPHL}	t _{RSKD}	Figures 6 and 9; $ V_{ID} \ge 2.0V$; rise and fall time of $V_{ID} \le 15$ ns		3	30	ns	
Receiver Enable to Output Low	t _{RZL}	Figures 5 and 10, $C_L = 100 pF$, S1 closed		20	50	ns	
Receiver Enable to Output High	t _{RZH}	Figures 5 and 10, $C_L = 100 pF$, S2 closed		20	50	ns	
Receiver Disable Time from Low	t _{RLZ}	Figures 5 and 10, $C_L = 100 pF$, S1 closed		20	50	ns	
Receiver Disable Time from High	t _{RHZ}	Figures 5 and 10, $C_L = 100 pF$, S2 closed		20	50	ns	
Time to Shutdown	$\mathbf{t}_{\mathrm{SHDN}}$	(Note 4)	50	200	600	ns	
Driver Enable from Shutdown to Output High	t _{DZH(SHDN)}	Figures 4 and 8, $C_L = 15 pF$, S2 closed			4500	ns	
Driver Enable from Shutdown to Output Low	t _{DZL(SHDN)}	Figures 4 and 8, $C_L = 15 pF$, S1 closed			4500	ns	
Receiver Enable from Shutdown to Output High	t _{RZH(SHDN)}	Figures 5 and 10, $C_L = 100 pF$, S2 closed			3500	ns	
Receiver Enable from Shutdown to Output Low	t _{RZL(SHDN)}	Figures 5 and 10, $C_L = 100 pF$, S1 closed			3500	ns	

Note 4: The device is put into shutdown by bringing \overline{RE} high and DE low. If the enable inputs are in this state for less than 50ns, the device is guaranteed not to enter shutdown. If the enable inputs are in this state for at least 600ns, the device is guaranteed to have entered shutdown.



Pin Description

Pin Number	Symbol	Function
1	RO	Receiver Output. If $A > B$ by -50mV, RO will be high; if $A < B$ by 200mV, RO will be low.
2	RE	Receiver Output Enable. Drive \overline{RE} low to enable Receiver, RO is high impedance when \overline{RE} is high. Drive \overline{RE} high and DE low to enter low-power shutdown mode.
3	DE	Driver Enable. Drive DE high to enable drivers. The outputs are high impedance when DE is low. Drive \overline{RE} high and DE low to enter low-power shutdown mode.
4	DI	Driver Input. A low on DI forces output A low and output B high. Similarly, a high on DI forces output A high and output B low.
5	GND	Ground
6	А	Non-inverting Receiver Input and Non-inverting Driver Output
7	В	Inverting Receiver Input and Inverting Driver Output,
8	V _{CC}	Power Supply for RS-485 transceiver

RS-485 Communication Function Table

Table1. Transmitting

	INPUTS		OUT	MODE	
\overline{RE}	DE	DI	В	А	MODE
Х	1	1	0	1	Normal
Х	1	0	1	0	Normal
0	0	Х	High-Z	High-Z	Normal
1	0	Х	High-Z	High-Z	Shutdown

X=Don't care; High-Z=High impedance

Table2. Receiving

INPUTS			OUTPUTS	MODE
RE	DE	A, B	RO	MODE
0	Х	>-50mV	1	Normal
0	Х	<-200mV	0	Normal
0	Х	Inputs Open	1	Normal
1	0	Х	High-Z	Shutdown

X=Don't care; High-Z=High impedance



Typical Operating Circuit

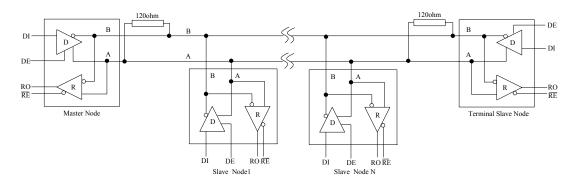


Figure 1. Typical Half-Duplex RS-485 Network

Test Circuit

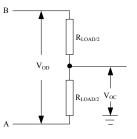


Figure 2. Driver DC Test Load

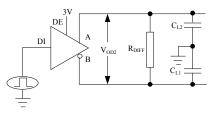
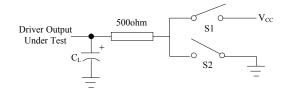


Figure 3. Driver Timing Test Circuit

Figure 5. Receiver Enable/Disable Timing Test Load



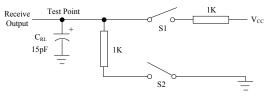


Figure 4. Driver Enable/Disable Timing Test Load

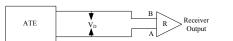


Figure 6. Receiver Propagation Delay Test Circuit



. /or.+0.5V

Vou-0.5V

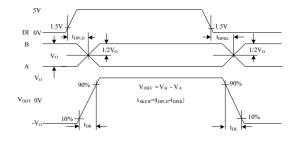


Figure 7. Driver Propagation Delays

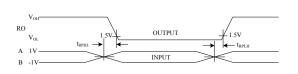




Figure 8. Driver Enable and Disable Times

Output Normally L

Output Normally High

t_{DZL(SHDN)}, t_{DZ}

30

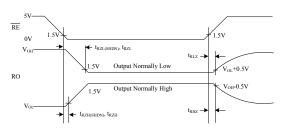


Figure 10. Receiver Enable and Disable Times

Detail Description

The UM3352E high-speed transceivers for RS-485 communication contain one driver and one receiver. The device features fail-safe circuitry, which guarantees a logic-high receiver output when the receiver input is open or shorted, or when it is connected to a terminated transmission line with all drivers disabled. The UM3352E features reduced slew-rate driver that minimizes EMI and reduces reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps. It operates from a single +5V supply. Drivers are output short-circuit current limited. Thermal shutdown circuitry protects drivers against excessive power dissipation. When activated, the thermal shutdown circuitry places the driver outputs into a high impedance state.

5V

V_{OL} V_{OH}

A Vo

в

DE 0V -----

Fail-Safe

The UM3352E guarantees a logic-high receiver output when the receiver inputs are shorted or open, or when they are connected to a terminated transmission line with all drivers disabled. This is done by setting the receiver threshold between -50mV and -200mV. If the differential receiver input voltage (A-B) is greater than or equal to -50mV, RO is logic high. If A-B is less than or equal to -200mV, RO is logic low. In the case of a terminated bus with all transmitters disabled, the receiver's differential input voltage is pulled to 0V by the termination. With the receiver thresholds of the UM3352E, this results in a logic high with a 50mV minimum noise margin. Unlike previous fail-safe devices, the -50mV to -200mV threshold complies with the \pm 200mV EIA/TIA-485 standard.



Applications Information

256 Transceivers on the Bus

The standard RS-485 receiver input impedance is $12k\Omega$ (one unit load), and the standard driver can drive up to 32 unit loads. The Union family of transceivers have a 1/8 unit load receiver input impedance (96k Ω), allowing up to 256 transceivers to be connected in parallel on one communication line. Any combination of these devices and/or other RS-485 transceivers with a total of 32 unit loads or less can be connected to the line.

Reduced EMI and Reflections

The UM3352E is slew-rate limited, minimizing EMI and reducing reflections caused by improperly terminated cables. In general, a transmitter's rise time relates directly to the length of an unterminated stub, which can be driven with only minor waveform reflections. The following equation expresses this relationship conservatively:

Length= $t_{RISE}/(10 \times 1.5 \text{ ns/ft})$

Where t_{RISE} is the transmitter's rise time.

A system can work well with longer unterminated stubs, even with severe reflections, if the waveform settles out before the UART samples them.

Low-Power Shutdown Mode

Low-power shutdown mode is initiated by bringing both \overline{RE} high and DE low. In shutdown, the

device typically draws only 2nA of supply current. \overline{RE} and DE may be driven simultaneously;

the parts are guaranteed not to enter shutdown if \overline{RE} is high and DE is low for less than 50ns. If the inputs are in this state for at least 600ns, the parts are guaranteed to enter shutdown. Enable times t_{ZH} and t_{ZL} in the Switching Characteristics tables assume the part was not in a low-power shutdown state. Enable times $t_{ZH(SHDN)}$ and $t_{ZL(SHDN)}$ assume the parts were shut down. It takes drivers and receivers longer to become enabled from low-power shutdown mode ($t_{ZH(SHDN)}$), $t_{ZL(SHDN)}$) than from driver/receiver-disable mode (t_{ZH} , t_{ZL}).

Driver Output Protection

Two mechanisms prevent excessive output current and power dissipation caused by faults or by bus contention. The first, a foldback current limit on the output stage, provides immediate protection against short circuits over the whole common-mode voltage range. The second, a thermal shutdown circuit, forces the driver outputs into a high-impedance state if the die temperature becomes excessive.

Line Length vs. Data Rate

The RS-485/RS-422 standard covers line lengths up to 4000 feet. For line lengths greater than 4000 feet, repeater is required.

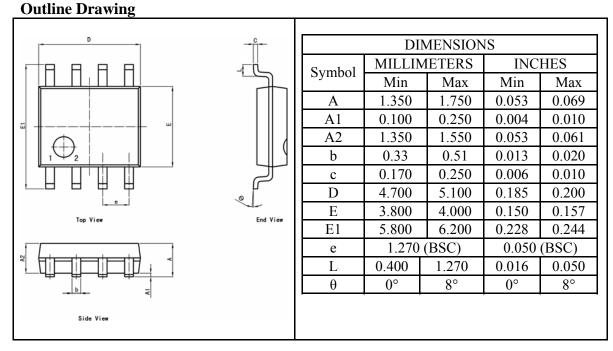
Typical Applications

The UM3352E transceivers are designed for bidirectional data communications on multipoint bus transmission lines. To minimize reflections, the line should be terminated at both ends in its characteristic impedance, and stub lengths off the main line should be kept as short as possible.

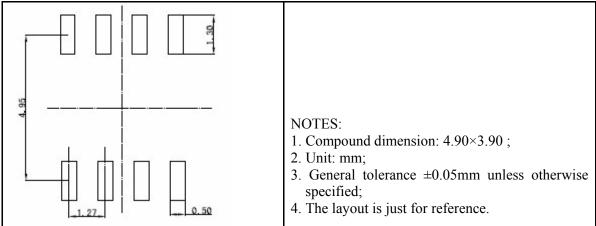


Package Information

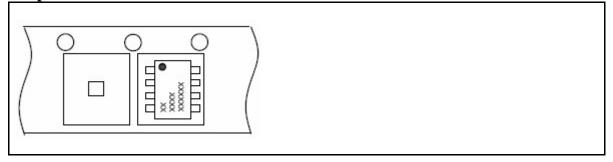
SOP8



Land Pattern

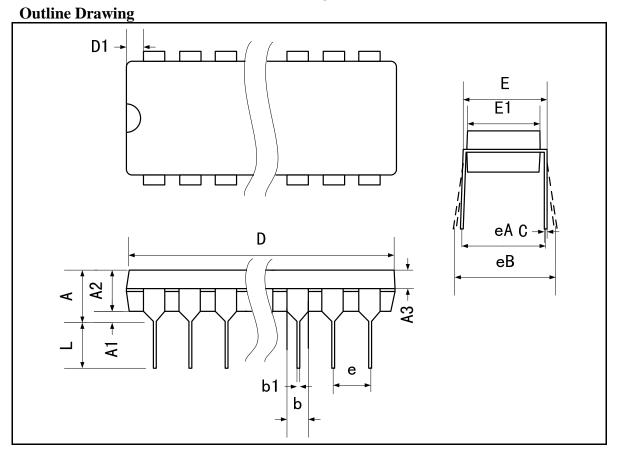


Tape and Reel Orientation





DIP8



	DIMENSIONS						
Symbol	MILLI	METERS	INC	HES			
Symbol	Min	Max	Min	Max			
А	-	5.08	-	0.200			
A1	0.38	-	0.015	-			
A2	3.18	4.45	0.125	0.175			
A3	1.40	2.03	0.055	0.080			
b	0.41	0.56	0.016	0.022			
b1	1.14	1.65	0.045	0.065			
С	0.20	0.30	0.008	0.012			
D (8 PIN)	8.84	9.91	0.348	0.390			
D1	0.13	2.03	0.005	0.080			
E	7.62	8.26	0.300	0.325			
E1	6.10	7.87	0.240	0.310			
e	2.54	-	0.100	-			
eA	7.62	-	0.300	-			
eB	-	10.16	-	0.400			
L	2.92	3.81	0.115	0.150			



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